General Purpose Transistor

NPN Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-323/SC-70 package which is designed for low power surface mount applications.

Features

- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V_{CEO}	40	Vdc
Collector - Base Voltage	V _{CBO}	75	Vdc
Emitter – Base Voltage	V _{EBO}	6.0	Vdc
Collector Current - Continuous	Ic	600	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board T _A = 25°C	P _D	150	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

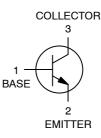


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SC-70 CASE 419 STYLE 3



MARKING DIAGRAM



P1 = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT2222AWT1G	SC-70 (Pb-Free)	3,000 / Tape & Reel
SMMBT2222AWT1G	SC-70 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

${\tt MMBT2222AWT1G,\,SMMBT2222AWT1G}$

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Charac	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (No $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	40	-	Vdc		
Collector – Base Breakdown Voltage ($I_C = 10 \mu Adc, I_E = 0$)	V _{(BR)CBO}	75	_	Vdc		
Emitter – Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$)		V _{(BR)EBO}	6.0	_	Vdc	
Base Cutoff Current (V _{CE} = 60 Vdc, V _{EB} = 3.0 Vdc)	I _{BL}	-	20	nAdc		
Collector Cutoff Current (V _{CE} = 60 Vdc, V _{EB} = 3.0 Vdc)	I _{CEX}	-	10	nAdc		
ON CHARACTERISTICS (Note 1)				_		
DC Current Gain (Note 1) $ \begin{aligned} &(I_C = 0.1 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \\ &(I_C = 1.0 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \\ &(I_C = 10 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \\ &(I_C = 150 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \\ &(I_C = 500 \text{ mAdc, } V_{CE} = 10 \text{ Vdc)} \end{aligned} $		H _{FE}	35 50 75 100 40	- - 300 -	-	
Collector – Emitter Saturation Voltage (Not $(I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc})$ $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$	V _{CE(sat)}	- -	0.3 1.0	Vdc		
Base – Emitter Saturation Voltage (Note 1) (I_C = 150 mAdc, I_B = 15 mAdc) (I_C = 500 mAdc, I_B = 50 mAdc)	V _{BE(sat)}	0.6	1.2 2.0	Vdc		
SMALL-SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product (I _C = 20 mAdc, V _{CE} = 20 Vdc, f = 100 M	1Hz)	f⊤	300	_	MHz	
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)		C _{obo}	-	8.0	pF	
Input Capacitance ($V_{EB} = 0.5 \text{ Vdc}$, $I_C = 0$, $f = 1.0 \text{ MHz}$)		C _{ibo}	-	30	pF	
Input Impedance ($V_{CE} = 10 \text{ Vdc}$, $I_{C} = 10 \text{ mAdc}$, $f = 1.0 \text{ kHz}$	Hz)	h _{ie}	0.25	1.25	kΩ	
Voltage Feedback Ratio $(V_{CE} = 10 \text{ Vdc}, I_C = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$	h _{re}	-	4.0	X 10 ⁻⁴		
Small – Signal Current Gain $(V_{CE} = 10 \text{ Vdc}, I_C = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$	h _{fe}	75	375	_		
Output Admittance ($V_{CE} = 10 \text{ Vdc}$, $I_{C} = 10 \text{ mAdc}$, $f = 1.0 \text{ kHz}$	h _{oe}	25	200	μmhos		
Noise Figure (V_{CE} = 10 Vdc, I_{C} = 100 μ Adc, R_{S} = 1.0	NF	-	4.0	dB		
SWITCHING CHARACTERISTICS						
Delay Time	$(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc},$	t _d	-	10	ns	
Rise Time	$I_C = 150 \text{ mAdc}, I_{B1} = 15 \text{ mAdc})$	t _r	-	25	1,0	
Storage Time	$(V_{CC} = 30 \text{ Vdc}, I_{C} = 150 \text{ mAdc},$	t _s	_	225	ns	
Fall Time	$I_{B1} = I_{B2} = 15 \text{ mAdc}$	t _f	-	60		

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUITS

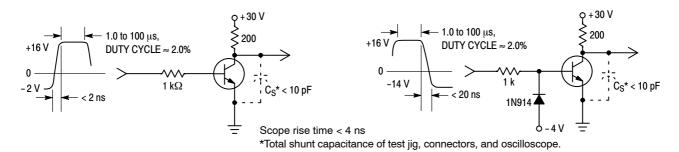


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

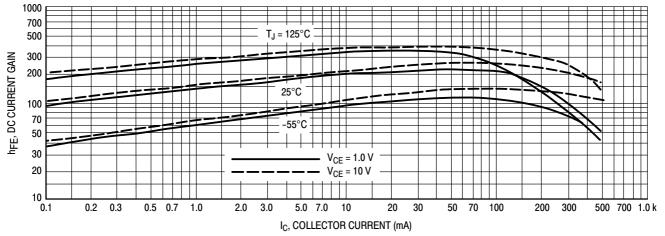


Figure 3. DC Current Gain

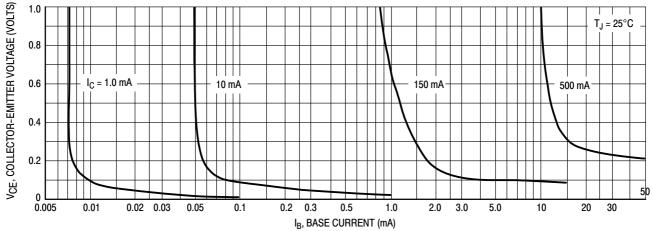


Figure 4. Collector Saturation Region

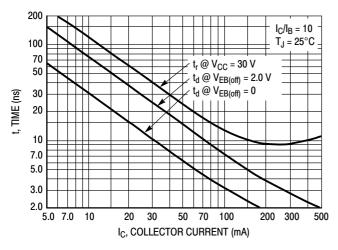


Figure 5. Turn - On Time

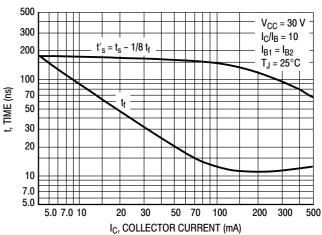


Figure 6. Turn - Off Time

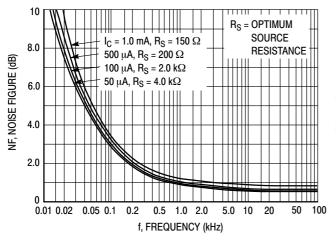


Figure 7. Frequency Effects

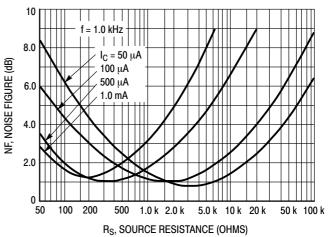


Figure 8. Source Resistance Effects

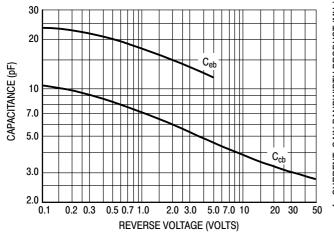


Figure 9. Capacitances

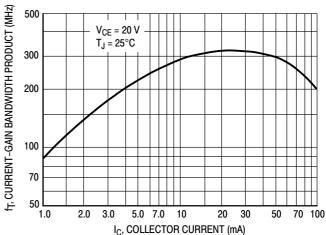


Figure 10. Current-Gain Bandwidth Product

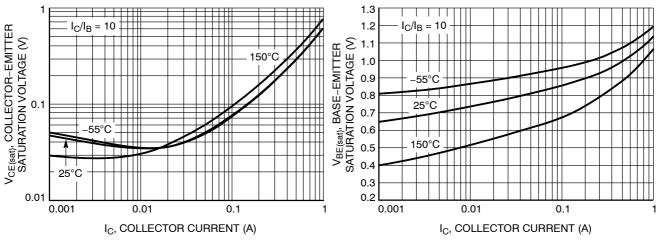


Figure 11. Collector Emitter Saturation Voltage vs. Collector Current



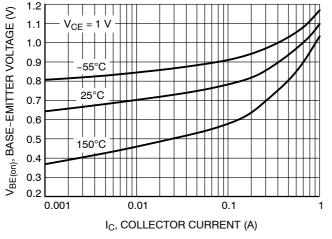


Figure 13. Base Emitter Voltage vs. Collector Current

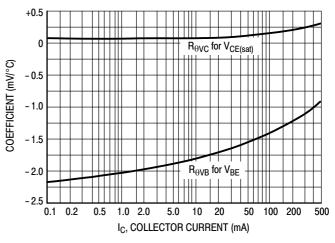


Figure 14. Temperature Coefficients

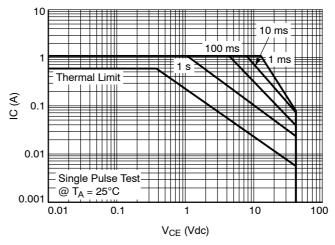
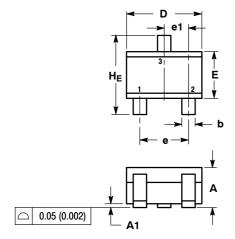
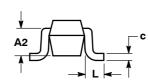


Figure 15. Safe Operating Area

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE N





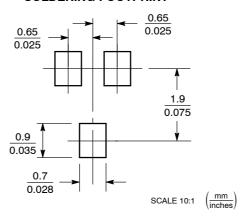
NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2		0.70 REF 0.028 REF				
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095

STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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